

#### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## HUF75345S3ST

### DESCRIPTION

- Drain Current: I<sub>D</sub>= 75A@ T<sub>C</sub>=25℃
- Drain Source Voltage
- : V<sub>DSS</sub>= 55V(Min)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

• Designed for high current, high speed switching, switch mode power supplies.

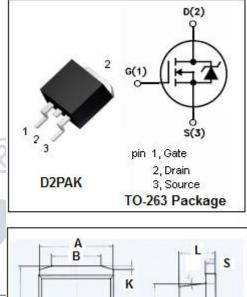
SYMBOL	ARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0) 55		v				
$V_{GS}$	Gate-Source Voltage	±20	v				
lo	Drain Current-continuous@ Tc=25°C 75		A				
P <sub>D</sub>	Total Dissipation@T <sub>C</sub> =25℃	325	W				
Tj	Max. Operating Junction Temperature	175	°C				
T <sub>stg</sub>	Storage Temperature Range -55~175		°C				
THERMAL CHARACTERISTICS							
SYMBOL	YMBOL PARAMETER		UNIT				

Thermal Resistance, Junction to Case

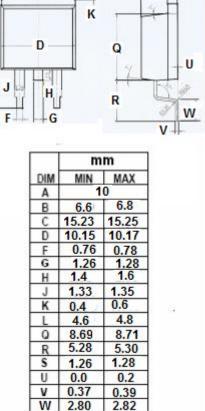
0.38

°C/W

### ABSOLUTE MAXIMUM RATINGS(Tc=25°C)



C



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R<sub>th j-c</sub>

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### • ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 250μA	55			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; Ι <sub>D</sub> =250μΑ	2.0		4.0	V
V <sub>SD</sub>	Diode Forward On-Voltage	I <sub>SD</sub> =75A ;V <sub>GS</sub> = 0			1.25	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =75A			7	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	$V_{GS}=\pm 20V; V_{DS}=0$			±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 50V; V <sub>GS</sub> = 0			1	-μA
		V <sub>DS</sub> = 40V; V <sub>GS</sub> = 0			250	

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